

FEATURES

With To-262 package

INCHANGE SEMICONDUCTOR

Isc N-Channel MOSFET Transistor

IRF520NL

D(2) · Low input capacitance and gate charge · Low gate input resistance 100% avalanche tested · Minimum Lot-to-Lot variations for robust device performance and reliable operation pin 1. Gate APPLICATIONS 2, Drain 3 · Switching applications 3, Source TO-262 package ABSOLUTE MAXIMUM RATINGS(Ta=25°C) VALUE SYMBOL PARAMETER UNIT VDSS 100 Drain-Source Voltage V Gate-Source Voltage ± 20 V V_{GSS} Drain Current-ContinuousTc=25°C 9.7 I_D А Tc=100°C 6.8 Drain Current-Single Pulsed lом 38 А mm MIN MAX DIM 4.77 4.37 A P_{D} Total Dissipation @T_c=25℃ 48 W 1.42 A1 22 A2 2.47 2.87 0.97 0.70 ь 1.17 1.42 b2 Max. Operating Junction Temperature °C T_{ch} 175 0.28 0.53 24.02 23.20 D1 8.38 8.90 D2 Storage Temperature -55~175 °C 6.00 Tsta Ε 9.90 10.39 E4 7.30 2.54BSC e 1.25 1.50 G THERMAL CHARACTERISTICS H2 1.31 13.34 14.10 L L1 3.30 4.06 SYMBOL MAX UNIT PARAMETER L3 0.95 1.15

isc website: www.iscsemi.cn

Channel-to-case thermal resistance

Rth(ch-c)

1

3.1

°C/W



Isc N-Channel MOSFET Transistor

IRF520NL

ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 0.25mA	100			v
V _{GS} (th)	Gate Threshold Voltage	V _{DS} =V _{GS} ; I _D =0.25mA	1.0		2.0	v
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =5.7A			200	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V;V _{DS} =0V			±0.1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} =100V; V _{GS} = 0V;Tj=25°C V _{DS} =80V; V _{GS} = 0V;Tj=125°C			25 250	μA
V _{SDF}	Diode forward voltage	I _{SD} =5.7A, V _{GS} = 0 V			1.3	V

NOTICE:

ISC reserves the rights to make changes of the content herein the datasheet at any time without notification. The information contained herein is presented only as a guide for the applications of our products.

ISC products are intended for usage in general electronic equipment. The products are not designed for use in equipment which require specialized quality and/or reliability, or in equipment which could have applications in hazardous environments, aerospace industry, or medical field. Please contact us if you intend our products to be used in these special applications. ISC makes no warranty or guarantee regarding the suitability of its products for any particular purpose, nor does ISC assume any liability arising from the application or use of any products, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages.

isc website: www.iscsemi.cn